



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

N-Channel Enhancement Mode Field Effect Transistor

VOLTAGE 100 Volts CURRENT 17 Ampere

CHM1710PAGP

APPLICATION

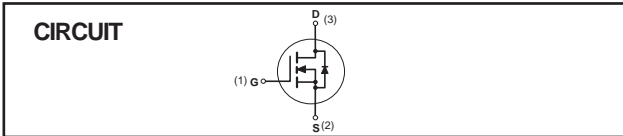
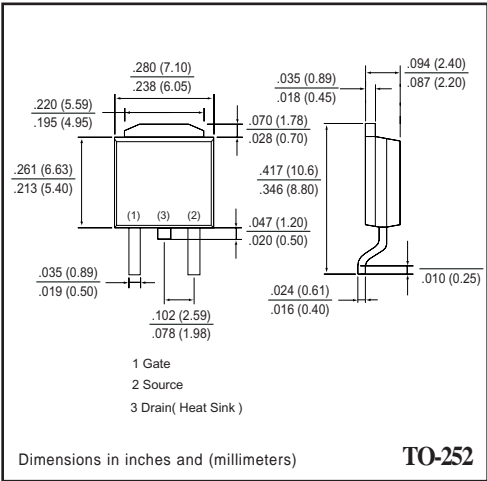
- * Servo motor control.
- * Power MOSFET gate drivers.
- * Other switching applications.

FEATURE

- * Small package. (TO-252)
- * Super high dense cell design for extremely low $R_{DS(ON)}$.
- * High power and current handling capability.

CONSTRUCTION

- * N-Channel Enhancement



Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | CHM1710PAGP | Units |
|-----------|-------------------------------------------------------|-------------|------------------|
| V_{DSS} | Drain-Source Voltage | 100 | V |
| V_{GSS} | Gate-Source Voltage | ± 20 | V |
| I_D | Maximum Drain Current - Continuous | 17 | A |
| | - Pulsed (Note 3) | 68 | |
| P_D | Maximum Power Dissipation at $T_c = 25^\circ\text{C}$ | 50 | W |
| T_J | Operating Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |

Note : 1. Surface Mounted on FR4 Board , $t \leq 10\text{sec}$
 2. Pulse Test , Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$
 3. Repetitive Rating , Pulse width limited by maximum junction temperature
 4. Guaranteed by design , not subject to production trsting

Thermal characteristics

| | | | |
|-----------------|--------------------------------------------------|----|--------------------|
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 1) | 50 | $^\circ\text{C/W}$ |
|-----------------|--------------------------------------------------|----|--------------------|

RATING CHARACTERISTIC CURVES (CHM1710PAGP)

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|--------|-----------|------------|-----|-----|-----|-------|
|--------|-----------|------------|-----|-----|-----|-------|

OFF CHARACTERISTICS

| | | | | | | |
|------------|---------------------------------|-----------------------------------------------|-----|--|------|---------------|
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$ | 100 | | | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$ | | | 1 | μA |
| I_{GSSF} | Gate-Body Leakage | $V_{GS} = 20\text{ V}, V_{DS} = 0\text{ V}$ | | | +100 | nA |
| I_{GSSR} | Gate-Body Leakage | $V_{GS} = -20\text{ V}, V_{DS} = 0\text{ V}$ | | | -100 | nA |

ON CHARACTERISTICS (Note 2)

| | | | | | | |
|--------------|-----------------------------------|-------------------------------------------|---|----|----|------------------|
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$ | 2 | | 4 | V |
| $R_{DS(on)}$ | Static Drain-Source On-Resistance | $V_{GS}=10\text{V}, I_D=15\text{A}$ | | 65 | 85 | $\text{m}\Omega$ |
| g_{FS} | Forward Transconductance | $V_{DS}=2.5\text{V}, I_D = 15\text{A}$ | | 11 | | S |

SWITCHING CHARACTERISTICS (Note 4)

| | | | | | | |
|-----------|--------------------|----------------------------------------------------------------------------------------|--|------|-----|----|
| Q_g | Total Gate Charge | $V_{DS}=80\text{V}, I_D=19\text{A}$ $V_{GS}=10\text{V}$ | | 26 | 34 | nC |
| Q_{gs} | Gate-Source Charge | | | 3.3 | | |
| Q_{gd} | Gate-Drain Charge | | | 16.2 | | |
| t_{on} | Turn-On Time | $V_{DD}= 50\text{V}$ $I_D=19\text{A}, V_{GS}= 10\text{ V}$ $R_{GEN}= 25\ \Omega$ | | 17 | 34 | nS |
| t_r | Rise Time | | | 51 | 100 | |
| t_{off} | Turn-Off Time | | | 16 | 32 | |
| t_f | Fall Time | | | 71 | 140 | |

DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS

| | | | | | |
|----------|------------------------------------|-----------------------------------------|--|-----|---|
| I_S | Drain-Source Diode Forward Current | | | 15 | A |
| V_{SD} | Drain-Source Diode Forward Voltage | $I_S = 15\text{A}, V_{GS} = 0\text{ V}$ | | 1.5 | V |

RATING CHARACTERISTIC CURVES (CHM1710PAGP)

Typical Electrical Characteristics

Figure 1. Output Characteristics

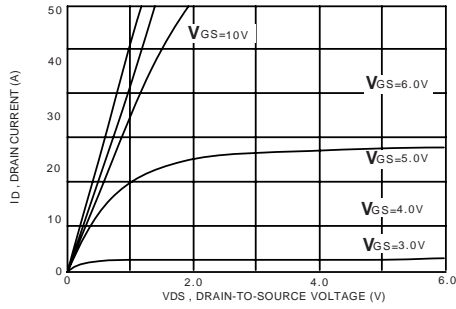


Figure 2. Transfer Characteristics

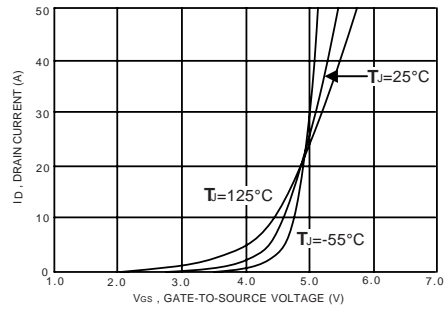


Figure 3. Gate Charge

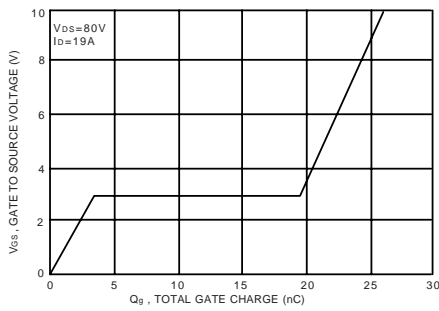


Figure 4. On-Resistance Variation with Temperature

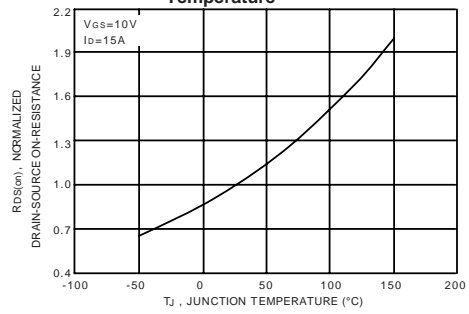


Figure 5. Gate Threshold Variation with Temperature

